BLC8G20LS-400AV

Power LDMOS transistor Rev. 4 — 24 November 2017

Product profile 1.

1.1 General description

400 W LDMOS packaged asymmetric Doherty power transistor for base station applications at frequencies from 1800 MHz to 2000 MHz.

Table 1. **Typical performance**

Typical RF performance at T_{case} = 25 °C in an asymmetrical Doherty production test circuit. V_{DS} = 32 V; I_{Dq} = 800 mA (main); $V_{GS(amp)peak}$ = 0.4 V, unless otherwise specified.

Test signal	f	V _{DS}	P _{L(AV)}	G _p	ησ	ACPR
	(MHz)	(V)	(W)	(dB)	(%)	(dBc)
1-carrier W-CDMA	1805 to 1880	32	85	15.5	44	-31 🛄
	1930 to 1990	32	85	15.5	44	-35 <u>[1]</u>

[1] Test signal: 1-carrier W-CDMA; 3GPP test model 1; 64 DPCH; PAR = 9.6 dB at 0.01% probability on CCDF.

1.2 Features and benefits

- Excellent ruggedness
- Excellent electrical stability
- Suitable for conventional and inverted Doherty
- High efficiency
- Low thermal resistance providing excellent thermal stability
- Lower output capacitance for improved performance in Doherty applications
- Designed for low memory effects providing excellent digital pre-distortion capability
- Internally matched for ease of use
- Integrated ESD protection
- Compliant to Directive 2002/95/EC, regarding Restriction of Hazardous Substances (RoHS)

1.3 Applications

RF power amplifiers for base stations and multi carrier applications in the 1800 MHz to 2000 MHz frequency range

Pinning information 2.

Pin	Description		Simplified outline	Graphic symbol
1	drain2 (peak)			
2	drain1 (main)			2, 7
3	gate1 (main)		5	
4	gate2 (peak)			35
5	source	<u>[1]</u>		
6	video decoupling (peak)			^и -т
7	video decoupling (main)			1, 6 <i>aaa-014884</i>

[1] Connected to flange.

Ordering information 3.

Table 3.	Ordering information
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Type number	Packag	Package				
	Name Description Vers					
BLC8G20LS-400AV	-	Air cavity plastic earless flanged package; 6 leads	SOT1258-1			

Limiting values 4.

Table 4. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions	Min	Max	Unit
V _{DS}	drain-source voltage		-	65	V
V _{GS(amp)main}	main amplifier gate-source voltage		-0.5	+13	V
V _{GS(amp)peak}	peak amplifier gate-source voltage		-0.5	+13	V
T _{stg}	storage temperature		-65	+150	°C
Tj	junction temperature	[1]	-	225	°C

[1] Continuous use at maximum temperature will affect the reliability, for details refer to the online MTF calculator.

Recommended operating conditions 5.

Table 5.	Operating conditions						
Symbol	Parameter	Conditions	Min	Max	Unit		
T _{case}	case temperature		-40	+125	°C		

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6. Thermal characteristics

Table 6.	Thermal characteristics			
Symbol	Parameter	Conditions	Тур	Unit
R _{th(j-c)}	thermal resistance from junction to case	V _{DS} = 32 V; I _{Dq} = 800 mA (main); V _{GS(amp)peak} = 0.4 V; T _{case} = 80 °C.		
		P _L = 85 W	0.32	K/W
		P _L = 110 W	0.31	K/W

7. Characteristics

Table 7. DC characteristics

 $T_j = 25 \ \mathcal{C}$ unless otherwise specified.

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
Main dev	ice					
V _{(BR)DSS}	drain-source breakdown voltage	V _{GS} = 0 V; I _D = 1.8 mA	65	-	-	V
V _{GS(th)}	gate-source threshold voltage	V _{DS} = 10 V; I _D = 180 mA	1.5	1.9	2.3	V
V _{GSq}	gate-source quiescent voltage	V _{DS} = 32 V; I _D = 800 mA	1.7	2.1	2.5	V
I _{DSS}	drain leakage current	V _{GS} = 0 V; V _{DS} = 28 V	-	-	2.8	μA
I _{DSX}	drain cut-off current	V _{GS} = V _{GS(th)} + 3.75 V; V _{DS} = 10 V	-	34	-	А
I _{GSS}	gate leakage current	V _{GS} = 11 V; V _{DS} = 0 V	-	-	280	nA
9 _{fs}	forward transconductance	V _{DS} = 10 V; I _D = 9.0 A	-	13	-	S
R _{DS(on)}	drain-source on-state resistance	V _{GS} = V _{GS(th)} + 3.75 V; I _D = 6.3 A	-	85	135	mΩ
Peak dev	ice					
V _{(BR)DSS}	drain-source breakdown voltage	V _{GS} = 0 V; I _D = 3.0 mA	65	-	-	V
V _{GS(th)}	gate-source threshold voltage	V _{DS} = 10 V; I _D = 300 mA	1.5	1.9	2.3	V
V _{GSq}	gate-source quiescent voltage	V _{DS} = 32 V; I _D = 1800 mA	1.7	2.1	2.5	V
I _{DSS}	drain leakage current	V _{GS} = 0 V; V _{DS} = 28 V	-	-	2.8	μA
I _{DSX}	drain cut-off current	V _{GS} = V _{GS(th)} + 3.75 V; V _{DS} = 10 V	-	50	-	А
I _{GSS}	gate leakage current	V _{GS} = 11 V; V _{DS} = 0 V	-	-	280	nA
9 _{fs}	forward transconductance	V _{DS} = 10 V; I _D = 15.0 A	-	19	-	S
R _{DS(on)}	drain-source on-state resistance	V _{GS} = V _{GS(th)} + 3.75 V; I _D = 10.5 A	-	55	85	mΩ

Table 8.RF characteristics

Test signal: 1-carrier W-CDMA; PAR = 9.6 dB at 0.01 % probability on the CCDF; 3GPP test model 1; 1 to 64 DPCH; $f_1 = 1807.5 \text{ MHz}$; $f_2 = 1877.5 \text{ MHz}$; RF performance at $V_{DS} = 32 \text{ V}$; $I_{Dq} = 800 \text{ mA}$ (main); $V_{GS(amp)peak} = 0.4 \text{ V}$; $T_{case} = 25 \text{ °C}$; unless otherwise specified; in an asymmetrical Doherty production test circuit in 1805 MHz to 1880 MHz frequency range.

Symbol	Parameter	Conditions	Min	Тур	Мах	Unit
G _p	power gain	P _{L(AV)} = 85 W	14.5	15.5	-	dB
RL _{in}	input return loss	P _{L(AV)} = 85 W	-	-11	-7	dB
η_D	drain efficiency	P _{L(AV)} = 85 W	40	44	-	%
ACPR	adjacent channel power ratio	P _{L(AV)} = 85 W	-	-31	-27	dBc
PARO	output peak-to-average ratio	P _{L(AV)} = 100 W	6.0	6.7	-	dB
P _{L(M)}	peak output power	P _{L(AV)} = 100 W	400	475	-	W

8. Test information

8.1 Ruggedness in Doherty operation

The BLC8G20LS-400AV is capable of withstanding a load mismatch corresponding to VSWR = 10 : 1 through all phases under the following conditions:

- V_{DS} = 28 V; I_{Dq} = 800 mA; V_{GS(amp)peak} = 0.4 V; f = 1807.5 MHz: 1-carrier W-CDMA; P_L = 141 W (5 dB OBO); 100 % clipping
- V_{DS} = 32 V; I_{Dq} = 800 mA; V_{GS(amp)peak} = 0.4 V; f = 1807.5 MHz: 1-carrier W-CDMA; P_L = 141 W (5 dB OBO); 100 % clipping

8.2 Impedance information

Table 9. Typical impedance of main device

Measured load-pull data of main device; I_{Dq} = 800 mA (main); V_{DS} = 32 V; pulsed CW (t_p = 100 μ s; δ = 10 %).

f	Z _S [1]	Z _L [1]	P _L [2]	η <mark>ρ ^[2]</mark>	G _p [2]
(MHz)	(Ω)	(Ω)	(W)	(%)	(dB)
Maximun	n power load				
1805	1.2 – j5.2	1.3 – j4.4	252	55.9	18.0
1840	1.2 – j5.3	1.2 – j4.5	249	55.6	18.1
1880	1.6 – j5.9	1.2 – j4.4	245	53.1	17.9
Maximun	n drain efficiency	load			
1805	1.2 – j5.2	2.5 – j4.0	178	61.4	20.0
1840	1.2 – j5.3	2.5 – j4.1	182	61.4	20.2
1880	1.6 – j5.9	2.6 – j3.9	176	60.8	20.5

[1] Z_S and Z_L defined in Figure 1.

[2] At 3 dB gain compression.

Table 10. Typical impedance of peak device

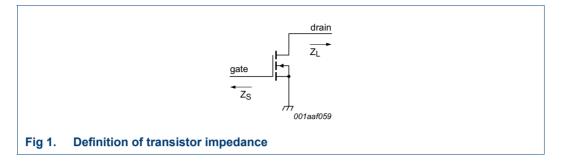
Measured load-pull data of peak device; I_{Dq} = 1750 mA (peak); V_{DS} = 32 V; pulsed CW (t_p = 100 μ s; δ = 10 %).

f	Z _S [1]	Z _L [1]	P _L [2]	η <mark>ρ <mark>[2]</mark></mark>	G _p [2]					
(MHz)	(Ω)	(Ω)	(W)	(%)	(dB)					
Maximu	Maximum power load									
1805	1.2 – j5.0	2.1 – j5.4	394	50.8	19.0					
1840	1.5 – j5.3	2.5 – j5.3	383	53.5	19.5					
1880	2.0 – j5.9	2.3 – j5.5	378	52.1	19.4					
Maximu	m drain efficiency	/ load								
1805	1.2 – j5.0	2.5 – j3.8	289	57.8	21.4					
1840	1.5 – j5.3	2.7 – j3.7	289	59.4	21.4					
1880	2.0 – j5.9	2.4 - j3.8	284	60.4	21.7					

[1] Z_S and Z_L defined in Figure 1.

[2] At 3 dB gain compression.

BLC8G20LS-400AV



8.3 Recommended impedances for Doherty design

Table 11. Typical impedance of main at 1 : 1 load

Measured load-pull data of main device; I_{Dq} = 800 mA (main); V_{DS} = 32 V; pulsed CW (t_p = 100 μ s; δ = 10 %).

f	Z _S ^[1]	Z _L ^[1]	P _{L(3dB)} [2]	η <mark>ρ ^[2]</mark>	G _p [2]
(MHz)	(Ω)	(Ω)	(W)	(%)	(dB)
1805	1.0 – j4.8	1.8 – j4.9	179	50.4	18.1
1840	1.1 – j5.0	1.7 – j4.6	189	51.6	18.3
1880	1.4 – j5.2	1.7 – j4.3	183	49.3	18.5

[1] Z_S and Z_L defined in Figure 1.

[2] At P_{L(AV)} = 85 W.

Table 12. Typical impedance of main device at 1 : 2.5 load

Measured load-pull data of main device; $I_{Dq} = 800 \text{ mA}$ (main); $V_{DS} = 32 \text{ V}$; pulsed CW ($t_p = 100 \mu s$; $\delta = 10 \%$).

f	Z _S [1]	Z _L [1]	P _{L(3dB)} [2]	ղ ը ^[2]	G _p [2]
(MHz)	(Ω)	(Ω)	(W)	(%)	(dB)
1805	1.0 – j4.8	3.1 – j3.5	132	51.1	19.7
1840	1.1 – j5.0	3.3 – j4.0	126	50.5	19.9
1880	1.4 – j5.2	3.3 – j4.2	126	50.7	19.9

[1] Z_S and Z_L defined in Figure 1.

[2] At P_{L(AV)} = 85 W.

Table 13. Typical impedance of peak device at 1 : 1 load

Measured load-pull data of peak device; I_{Dq} = 1750 mA (peak); V_{DS} = 32 V; pulsed CW (t_p = 100 μ s; δ = 10 %).

f	Z _S [1]	Z _L ^[1]	P _{L(3dB)} [2]	η <mark>ρ ^[2]</mark>	G _p [2]
(MHz)	(Ω)	(Ω)	(W)	(%)	(dB)
1805	1.2 – j5.0	2.8 – j4.8	316	50.0	19.0
1840	1.5 – j5.3	2.7 – j4.6	313	51.4	19.4
1880	2.0 – j5.9	2.6– j4.3	290	52.9	20.0

[1] Z_S and Z_L defined in Figure 1.

[2] At P_{L(AV)} = 85 W.

Table 14. Off-state impedances of peak device

f	Z _{off}
(MHz)	(Ω)
1805	0.9 – j0.2
1840	0.9 – j0.1
1880	0.9 – j0.2

8.4 Test circuit

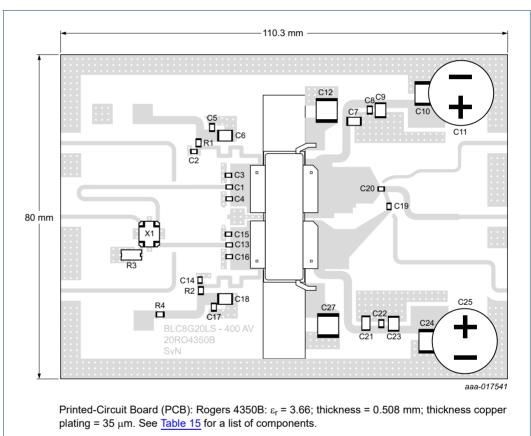


Fig 2. Component layout

Table 15.List of components

See Figure 2 for component layout.

Component	Description	Value		Remarks
C1, C2, C13, C14, C19	multilayer ceramic chip capacitor	10 pF	[1]	ATC 100A
C3, C15	multilayer ceramic chip capacitor	2.2 pF	[1]	ATC 100A
C4, C16	multilayer ceramic chip capacitor	2.0 pF	1]	ATC 100A
C5, C8, C17, C22	multilayer ceramic chip capacitor	100 nF	2]	Murata
C6, C9, C18, C23	multilayer ceramic chip capacitor	4.7 μF	2]	Murata
C7, C21	multilayer ceramic chip capacitor	10 pF	3]	ATC 100B
C10, C24	multilayer ceramic chip capacitor	10 μF, 50 V		TDK C5750X7

Table 15. List of components ... continued

See Figure 2 for component layo	ut.
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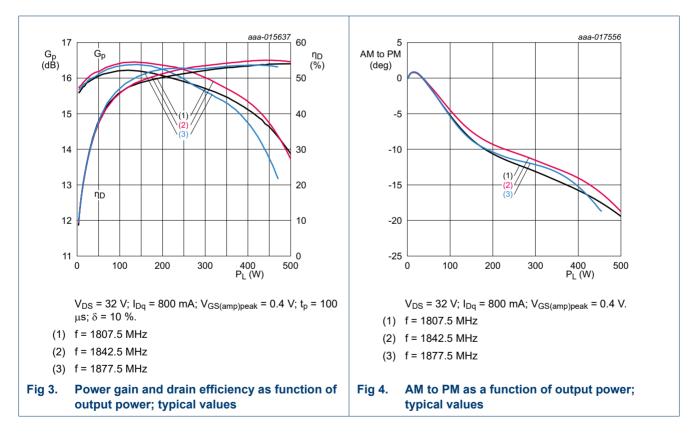
Component	Description	Value	Remarks
C11; C25	electrolytic capacitor	470 μF, 63 V	Vishay 148RUS
C12; C26	multilayer ceramic chip capacitor	4.7 μF, 100 V	TDK C5750X7
C20	multilayer ceramic chip capacitor	5.6 pF	
R1, R2	SMD resistor	4.7 Ω	SMD 0805
R3	SMD resistor	50 Ω	SMD 0805
R4	SMD resistor	470 Ω	SMD 0805
X1	directional coupler	5 dB	Anaren X3C19P1-05S

[1] American Technical Ceramics type 100A or capacitor of same quality.

- [2] Murata or capacitor of same quality.
- [3] American Technical Ceramics type 100B or capacitor of same quality.

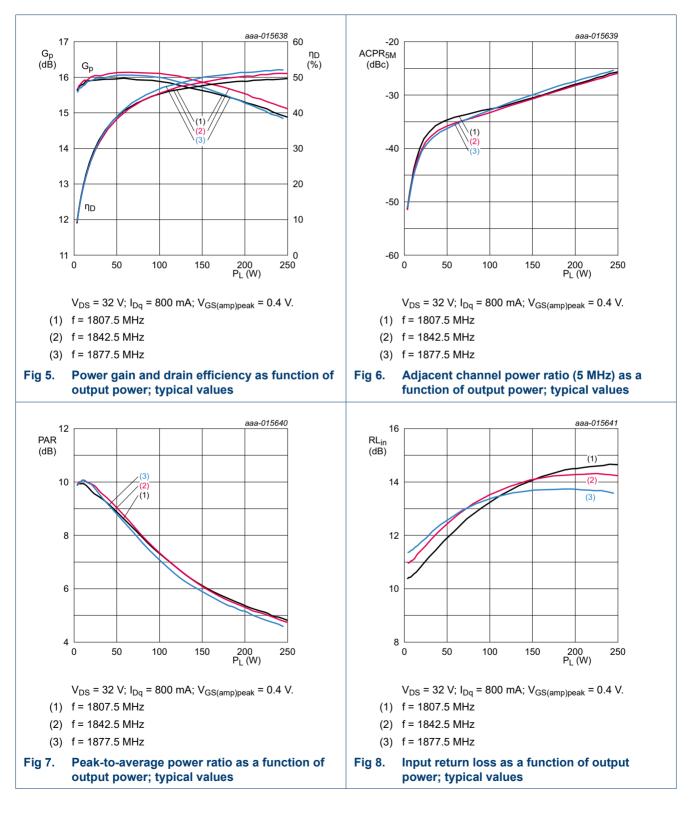
8.5 Graphical data

8.5.1 Pulsed CW



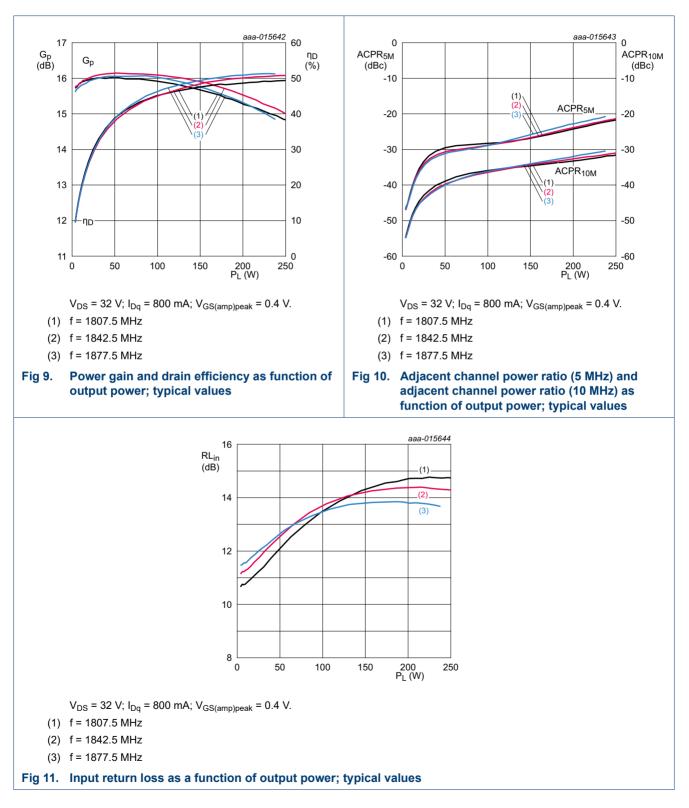
8.5.2 1-Carrier W-CDMA

PAR = 9.6 dB per carrier at 0.01 % probability on the CCDF; 3GPP test model 1 with 64 DPCH (100 % clipping).

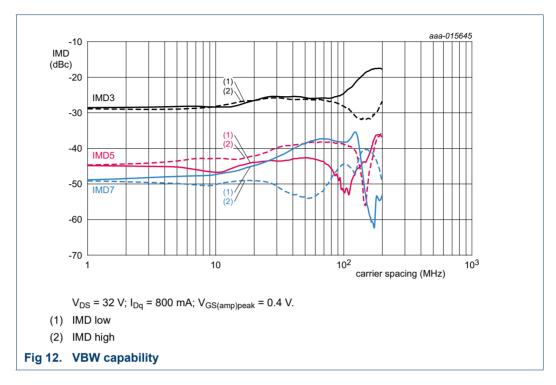


8.5.3 2-Carrier W-CDMA

PAR = 9.6 dB at 0.01 % probability on the CCDF; 3GPP test model 1 with 64 DPCH (46 % clipping).



8.5.4 2-Tone VBW



9. Package outline

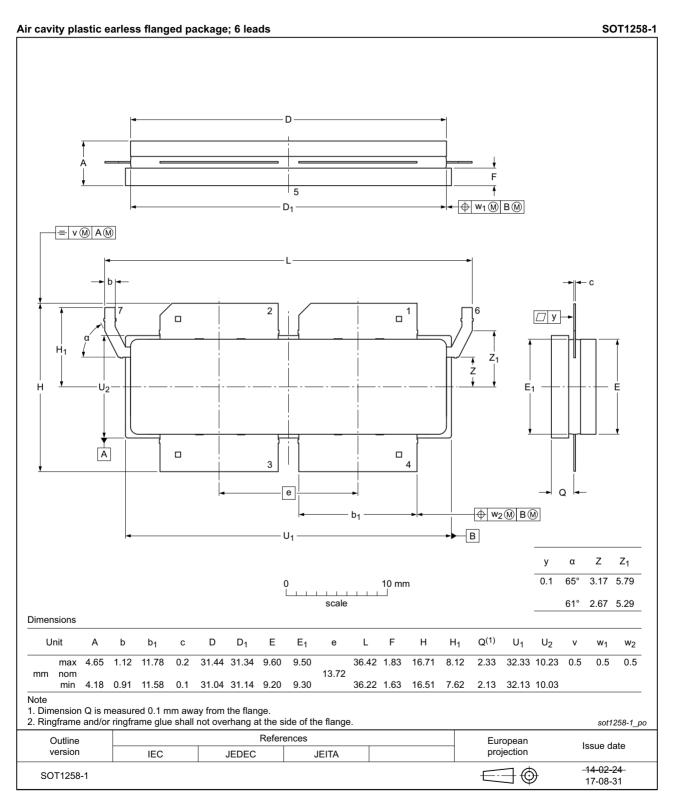


Fig 13. Package outline SOT1258-1

10. Handling information

CAUTION



This device is sensitive to ElectroStatic Discharge (ESD). Observe precautions for handling electrostatic sensitive devices.

Such precautions are described in the ANSI/ESD S20.20, IEC/ST 61340-5, JESD625-A or equivalent standards.

Table 16.ESD sensitivity

ESD model	Class
Charged Device Model (CDM); According to ANSI/ESDA/JEDEC star	ndard JS-002 C2A [1]
Human Body Model (HBM); According to ANSI/ESDA/JEDEC standa	rd JS-001 2 ^[2]

 CDM classification C2A is granted to any part that passes after exposure to an ESD pulse of 500 V, but fails after exposure to an ESD pulse of 750 V.

[2] HBM classification 2 is granted to any part that passes after exposure to an ESD pulse of 2000 V, but fails after exposure to an ESD pulse of 4000 V.

11. Abbreviations

Table 17. Abbreviations

Aaranum	Description
Acronym	Description
3GPP	3rd Generation Partnership Project
AM	Amplitude Modulation
CCDF	Complementary Cumulative Distribution Function
CW	Continuous Wave
DPCH	Dedicated Physical CHannel
ESD	ElectroStatic Discharge
LDMOS	Laterally Diffused Metal-Oxide Semiconductor
MTF	Median Time to Failure
OBO	Output Back Off
PAR	Peak-to-Average Ratio
PM	Phase Modulation
SMD	Surface Mounted Device
VBW	Video BandWidth
VSWR	Voltage Standing Wave Ratio
W-CDMA	Wideband Code Division Multiple Access

12. Revision history

Table 18. Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes
BLC8G20LS-400AV v.4	20171124	Product data sheet	-	BLC8G20LS-400AV v.3
Modifications:	• Table 3 on pa	nge 2: changed simplified vers nge 2: changed version SOT1: page 11: changed package o	258-3 to SOT1258-1	
BLC8G20LS-400AV v.3	20161202	Product data sheet	-	BLC8G20LS-400AV v.2
BLC8G20LS-400AV v.2	20150901	Product data sheet	-	BLC8G20LS-400AV v.1
BLC8G20LS-400AV v.1	20150326	Product data sheet	-	-

13. Legal information

13.1 Data sheet status

Document status ^{[1][2]}	Product status ^[3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

[1] Please consult the most recently issued document before initiating or completing a design.

[2] The term 'short data sheet' is explained in section "Definitions".

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Document identifier: BLC8G20LS-400AV